# Low Frequency Transistor (20V, 3A) **2SC4115S**

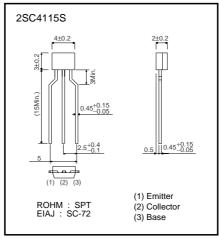
#### Features

- 1) Low VCE(sat). VCE(sat) = 0.2V(Typ.) (Ic / IB = 2A / 0.1A)
- 2) Excellent current gain characteristics.
- 3) Complements the 2SA1585S.

#### ●Structure

Epitaxial planar type NPN silicon transistor

# ●External dimensions (Unit : mm)



\* Denotes hre

# ● Absolute maximum ratings (Ta=25°C)

| Parameter                   | Symbol | Limits      | Unit        |
|-----------------------------|--------|-------------|-------------|
| Collector-base voltage      | Vсво   | 40          | V           |
| Collector-emitter voltage   | Vceo   | 20          | V           |
| Emitter-base voltage        | VEBO   | 6           | V           |
| Collector current           | Ic     | 2           | A (DC)      |
|                             |        | 5           | A (Pulse) * |
| Collector power dissipation | Pc     | 0.4         | W           |
| Junction temperature        | Tj     | 150         | °C          |
| Storage temperature         | Tstg   | -55 to +150 | °C          |

<sup>\*</sup> Single pulse Pw=10ms

# ●Electrical characteristics (Ta=25°C)

| Parameter                            | Symbol   | Min. | Тур. | Max. | Unit | Conditions                   |
|--------------------------------------|----------|------|------|------|------|------------------------------|
| Collector-base breakdown voltage     | ВУсво    | 40   | _    | _    | V    | Ic=50μA                      |
| Collector-emitter breakdown voltage  | BVceo    | 20   | _    | _    | V    | Ic=1mA                       |
| Emitter-base breakdown voltage       | ВУево    | 6    | _    | _    | V    | Iε=50μA                      |
| Collector cutoff current             | Ісво     | _    | _    | 0.1  | μΑ   | Vcb=30V                      |
| Emitter cutoff current               | ІЕВО     | _    | _    | 0.1  | μΑ   | V <sub>EB</sub> =5V          |
| Collector-emitter saturation voltage | VCE(sat) | _    | 0.2  | 0.5  | V    | Ic/I <sub>B</sub> =2A/0.1A * |
| DC current transfer ratio            | hfe      | 120  | -    | 390  | -    | Vce=2V, Ic=0.1A              |
| Transition frequency                 | f⊤       | _    | 290  | _    | MHz  | Vce=2V, Ie= -0.5A, f=100MHz  |
| Output capacitance                   | Cob      | -    | 25   | _    | pF   | Vce=10V, Ie=0A, f=1MHz       |

<sup>\*</sup> Measured using pulse current.

# ●Packaging specifications and hFE

|          |     | Package                      | Taping |
|----------|-----|------------------------------|--------|
|          |     | Code                         | TP     |
| Туре     | hfe | Basic ordering unit (pieces) | 5000   |
| 2SC4115S | QRS |                              | 0      |

### hre values are classified as follows:

| Item | Q          | R          | S          |
|------|------------|------------|------------|
| hfe  | 120 to 270 | 180 to 390 | 270 to 560 |

#### Electrical characteristic curves

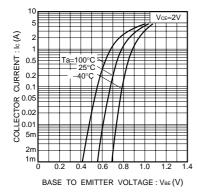


Fig.1 Grounded emitter propagation characteristics

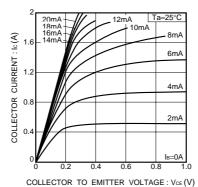


Fig.2 Grounded emitter output characteristics ( I )

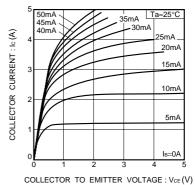


Fig.3 Grounded emitter output characteristics ( II )



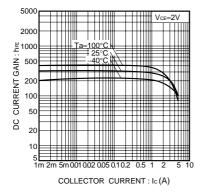


Fig.4 DC current gain vs. collector current

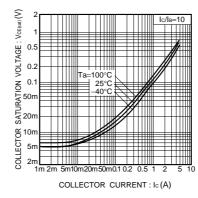


Fig.5 Collector-emitter saturation voltage vs. collector current ( I )

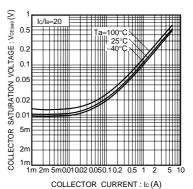


Fig.6 Collector-emitter saturation voltage vs. collector current (II)

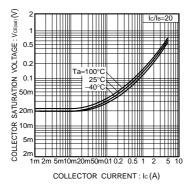


Fig.7 Collector-emitter saturation voltage vs. collector current (III)

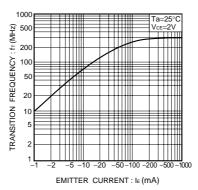


Fig.8 Gain bandwidth product vs. emitter current

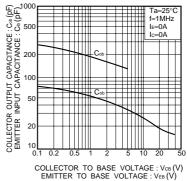


Fig.9 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

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